## 國立成功大學 103 學年度碩士班招生考試試題

系所組別:工程科學系甲、戊組

考試科目:電子電路

編號: 130

考試日期:0223,節次:1

※ 考生請注意:本試題可使用計算機。 請於答案卷(卡)作答,於本試題紙上作答者,不予計分。請依 題號順序作答。

- 1. Mark each of the following statements True (T) or False (F). (Need NOT to give reasons.) (20 分)
  - (a) When performing DC analysis, the capacitors including coupling, bypass, and internal parasitic capacitors should be opened circuit because their impedances are zero.
  - (b) When performing low-frequency response analysis, the coupling and bypass capacitors should be analyzed, while internal parasitic capacitors should be shorted circuit.
  - (c) When performing high-frequency response analysis, the internal parasitic capacitors should be analyzed, while coupling and bypass capacitors should be opened circuit.
  - (d) The ideal voltage amplifier has infinite input resistance, zero output resistance, and infinite voltage gain.
  - (e) The common drain amplifier can be used to obtain the bulk of the voltage gain.
  - (f) The input stage of an operational amplifier typically uses the differential amplifier to reject the common-mode signals.
  - (g) Feedback can be used to extend the bandwidth of an amplifier.
  - (h) Feedback cannot desensitize the closed-loop gain introduced by the variation of the open-loop gain of the basic amplifier.
  - (i) The current mirror is typically employed to bias the discrete-component circuits.
  - (j) The saturation region of an MOS is used to amplify the small signals.
- 2. The amplifier consists of two identical common-emitter amplifiers connected in cascade.  $V_{CC} = 15$  V,  $R_1 = 100$ K $\Omega$ ,  $R_2 = 47$ K $\Omega$ ,  $R_E = 3.9$ K $\Omega$ ,  $R_C = 6.8$ K $\Omega$ ,  $\beta = 100$  and  $V_T = 25$  mV. Neglect the output resistance  $r_{o1}$  and  $r_{o1}$  for both transistors. (a) Determine the DC collector current and collector voltage of each transistor. (4  $\hat{\gamma}$ ) (b) Find  $R_{in1}$  and  $v_{b1}/v_s$  for  $R_S = 5$ K $\Omega$ . (4  $\hat{\gamma}$ ) (c) Find  $R_{in2}$  and  $v_{b2}/v_{b1}$ . (4  $\hat{\gamma}$ ) (d) For  $R_L = 2$ K $\Omega$ , find  $v_a/v_{b2}$ . (4  $\hat{\gamma}$ ) (e) Find the overall voltage gain  $v_a/v_s$ . (4  $\hat{\gamma}$ )





 $V_A = 1/\lambda = \infty$ .  $R_1 = 500\Omega$  and  $R_2 = 250\Omega$ . (a) Determine the bias drain current of  $Q_3$ . (6  $\Re$ ) (b) Determine the small-signal voltage gain. (8  $\Re$ ) (c) What is the allowed range of  $v_i$  for  $Q_1$ ,  $Q_2$  and  $Q_3$  operating in the saturation region? (6  $\Re$ )

 $v_i \circ Q_3$   $Q_2$   $Q_2$   $Q_2$   $Q_2$   $Q_1$   $Q_1$ 

4. For the circuit shown below, the transistor has  $\frac{1}{2}k'_{n}\left(\frac{W}{L}\right) = 1 \text{ mA/V}^{2}$ ,  $V_{t} = 0.8 \text{ V}$ ,  $r_{o} = \infty$ ,  $C_{gs} = 2 p\text{F}$ , and  $C_{gd} = 0.2 p\text{F}$ . Determine: (a) the midband voltage gain  $V_{o}/V_{i}$  (10 %), and (b) the upper 3-dB frequency,  $f_{H}$  in Hz. (10 %). Hint: You can apply Miller's theorem and, then use the open-ckt time constant.



編號: 130 國立成功大學 103 學年度碩士班招生考試試題	共 3 頁,第3頁
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5. The transistors $Q_1$ and $Q_2$ have $h_{fe} = 80$ and $V_T = 25 \text{ mV}$ , and are biased at $I_{c1} = 0.2 \text{ mA}$ and	
$I_{c2}=8~{ m mA}$ , respectively. (a) What are the feedback $eta$ and the <i>current gain</i> of basic amplifier A? (10 分)	
(b) Find $A_f \equiv V_o / V_S$ and $R_{in}$ . (10 $\hat{\mathcal{T}}$ )	

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